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FDD5N50U

N-Channel UniFET™ Ultra FRFET™ MOSFET

500 V, 3 A, 2.0 Ω

Features

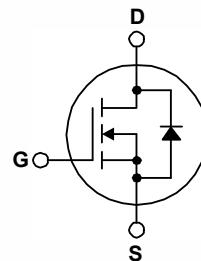
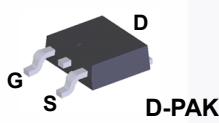
- $R_{DS(on)} = 1.65 \Omega$ (Typ.) @ $V_{GS} = 10$ V, $I_D = 1.5$ A
- Low Gate Charge (Typ. 11 nC)
- Low C_{rss} (Typ. 5 pF)
- 100% Avalanche Tested
- RoHS Compliant

Applications

- LCD/LED/PDP TV
- Lighting
- Uninterruptible Power Supply

Description

UniFET™ MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. UniFET Ultra FRFET™ MOSFET has much superior body diode reverse recovery performance. Its t_{rr} is less than 50nsec and the reverse dv/dt immunity is 20V/nsec while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore UniFET Ultra FRFET MOSFET can remove additional component and improve system reliability in certain applications that require performance improvement of the MOSFET's body diode. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter		FDD5N50UTM_WS	Unit
V_{DSS}	Drain to Source Voltage		500	V
V_{GSS}	Gate to Source Voltage		± 30	V
I_D	Drain Current	- Continuous ($T_C = 25^\circ\text{C}$)	3	A
		- Continuous ($T_C = 100^\circ\text{C}$)	1.8	
I_{DM}	Drain Current	- Pulsed	(Note 1)	12
E_{AS}	Single Pulsed Avalanche Energy		(Note 2)	275
I_{AR}	Avalanche Current		(Note 1)	3
E_{AR}	Repetitive Avalanche Energy		(Note 1)	4
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5
P_D	Power Dissipation	($T_C = 25^\circ\text{C}$)	40	W
		- Derate Above 25°C	0.3	
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +150	$^\circ\text{C}$
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	FDD5N50UTM_WS	Unit
$R_{\theta,JC}$	Thermal Resistance, Junction to Case, Max.	1.4	$^\circ\text{C}/\text{W}$
$R_{\theta,JA}$	Thermal Resistance, Junction to Ambient, Max.	110	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDD5N50UTM_WS	FDD5N50U	DPAK	Tape and Reel	330 mm	16 mm	2500 units

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}, T_J = 25^\circ\text{C}$	500	-	-	V
$\Delta \text{BV}_{\text{DSS}} / \Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu\text{A}, \text{Referenced to } 25^\circ\text{C}$	-	0.6	-	$^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 500 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	25	μA
		$V_{DS} = 400 \text{ V}, T_C = 125^\circ\text{C}$	-	-	250	
I_{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	± 100	nA

On Characteristics

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	3	-	5	V
$R_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 1.5 \text{ A}$	-	1.65	2.0	Ω
g_{FS}	Forward Transconductance	$V_{DS} = 20 \text{ V}, I_D = 1.5 \text{ A}$	-	4	-	S

Dynamic Characteristics

C_{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-	485	650	pF
C_{oss}	Output Capacitance		-	65	90	pF
C_{rss}	Reverse Transfer Capacitance		-	5	8	pF
$Q_{g(\text{tot})}$	Total Gate Charge at 10V	$V_{DS} = 400 \text{ V}, I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}$	-	11	15	nC
Q_{gs}	Gate to Source Gate Charge		-	3	-	nC
Q_{gd}	Gate to Drain "Miller" Charge		(Note 4)	-	5	nC

Switching Characteristics

$t_{d(\text{on})}$	Turn-On Delay Time	$V_{DD} = 250 \text{ V}, I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}, R_G = 25 \Omega$	-	14	38	ns
t_r	Turn-On Rise Time		-	21	52	ns
$t_{d(\text{off})}$	Turn-Off Delay Time		-	27	64	ns
t_f	Turn-Off Fall Time		(Note 4)	-	20	50

Drain-Source Diode Characteristics

I_S	Maximum Continuous Drain to Source Diode Forward Current	-	-	3	A	
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current	-	-	12	A	
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 3 \text{ A}$	-	-	1.6	V
t_{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V}, I_{SD} = 5 \text{ A}, dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	36	-	ns
Q_{rr}	Reverse Recovery Charge	-	33	-	nC	

Notes:

- 1: Repetitive rating: pulse width limited by maximum junction temperature.
- 2: $L = 61 \text{ mH}, I_{AS} = 3 \text{ A}, V_{DD} = 50 \text{ V}, R_G = 25 \Omega$, starting $T_J = 25^\circ\text{C}$.
- 3: $I_{SD} \leq 3 \text{ A}, dI/dt \leq 200 \text{ A}/\mu\text{s}, V_{DD} \leq \text{BV}_{\text{DSS}}$, starting $T_J = 25^\circ\text{C}$.
- 4: Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

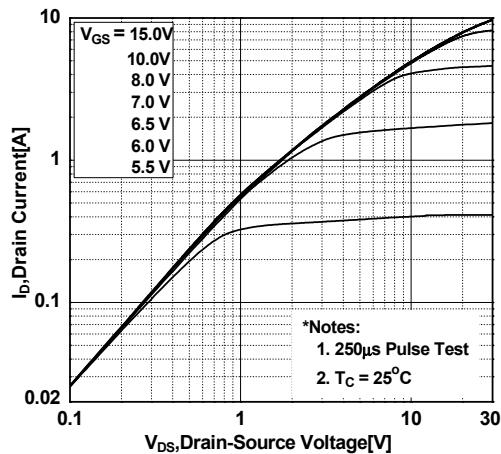


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

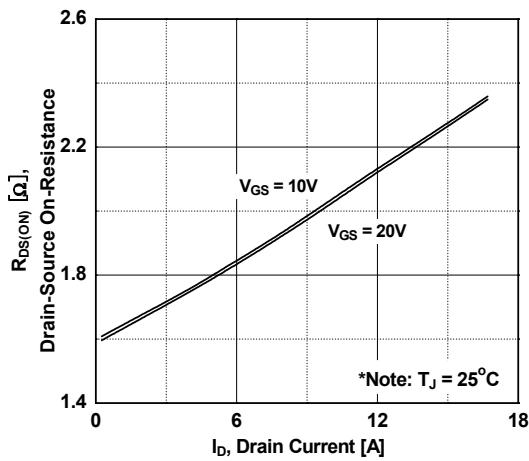


Figure 5. Capacitance Characteristics

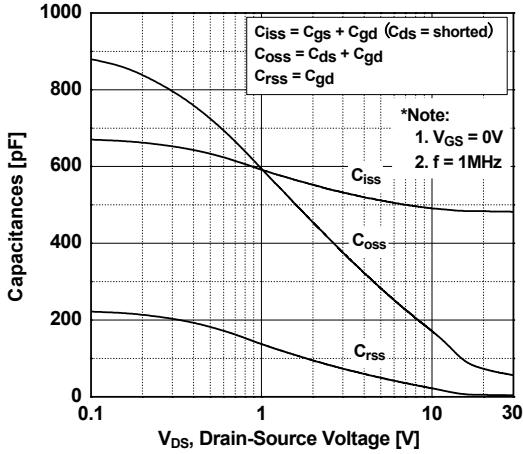


Figure 2. Transfer Characteristics

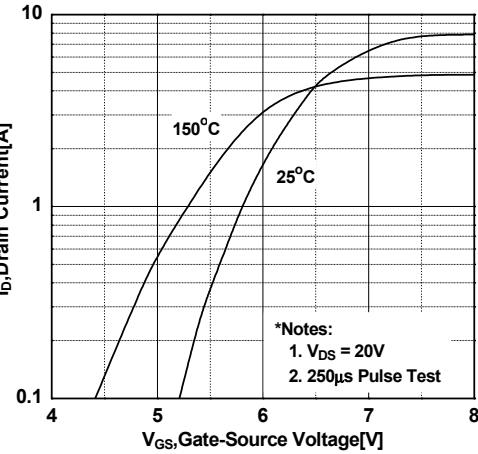


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

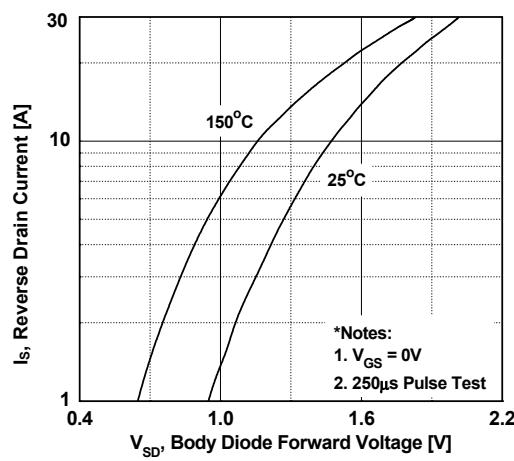
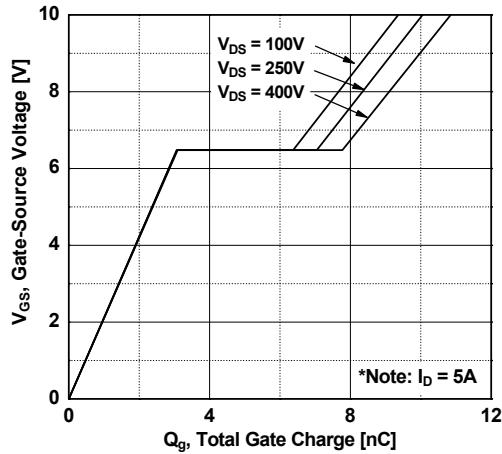


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

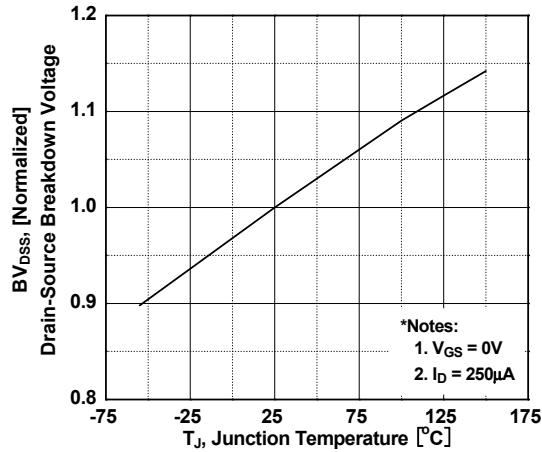


Figure 8. Maximum Safe Operating Area

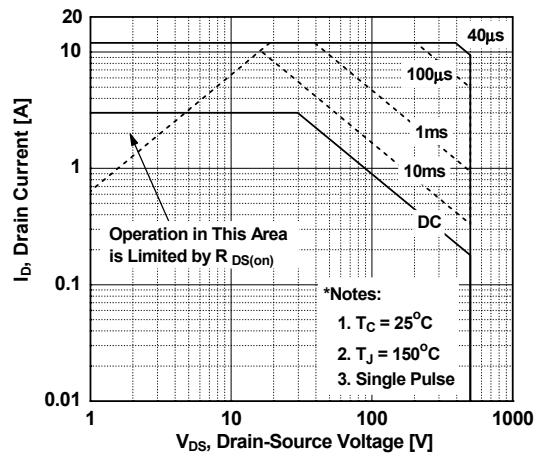


Figure 9. Maximum Drain Current vs. Case Temperature

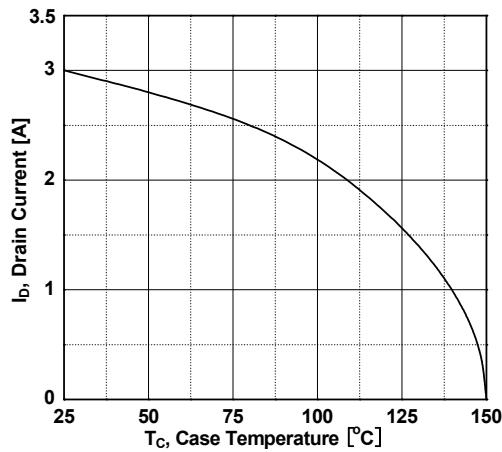
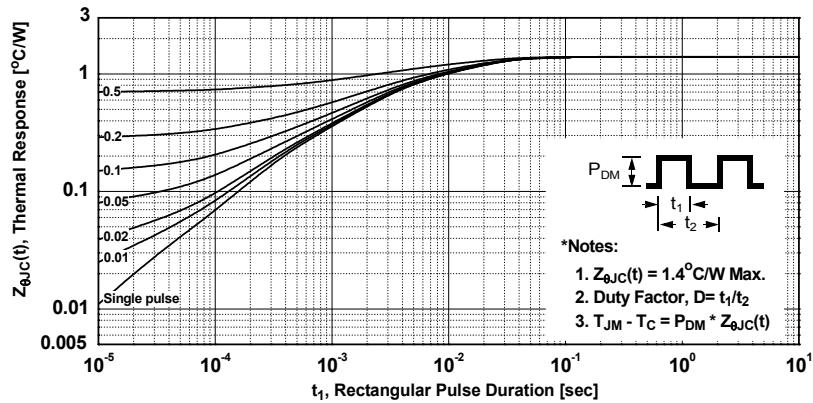


Figure 10. Transient Thermal Response Curve



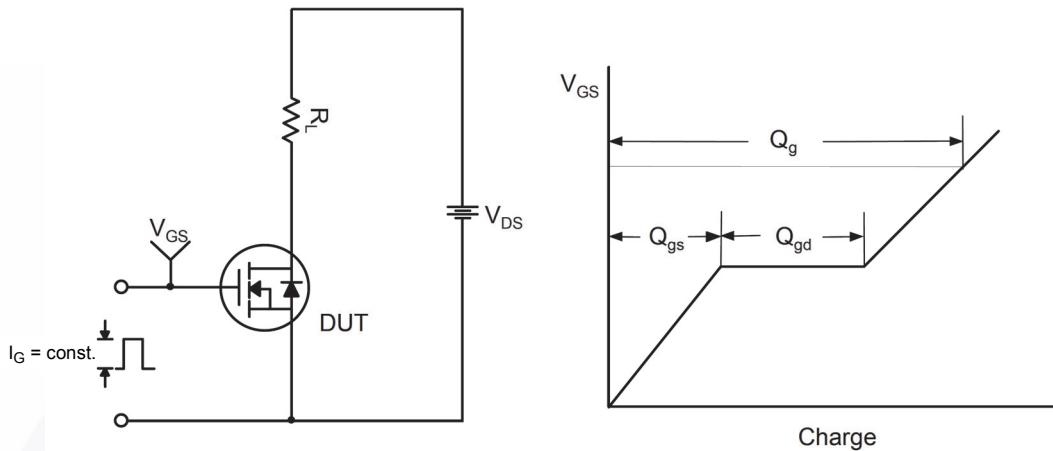


Figure 11. Gate Charge Test Circuit & Waveform

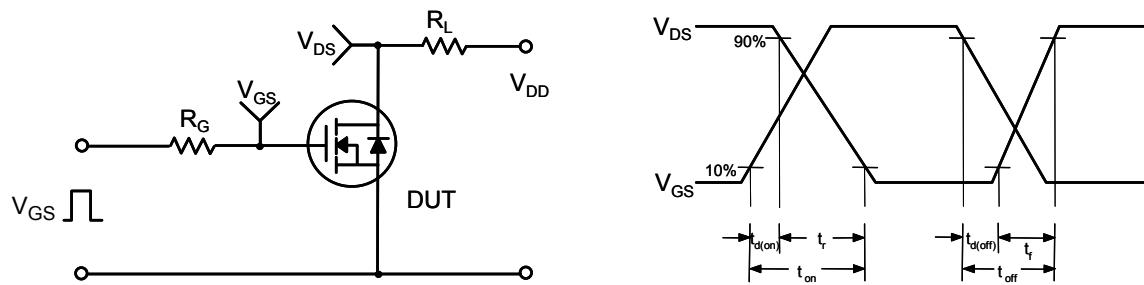


Figure 12. Resistive Switching Test Circuit & Waveforms

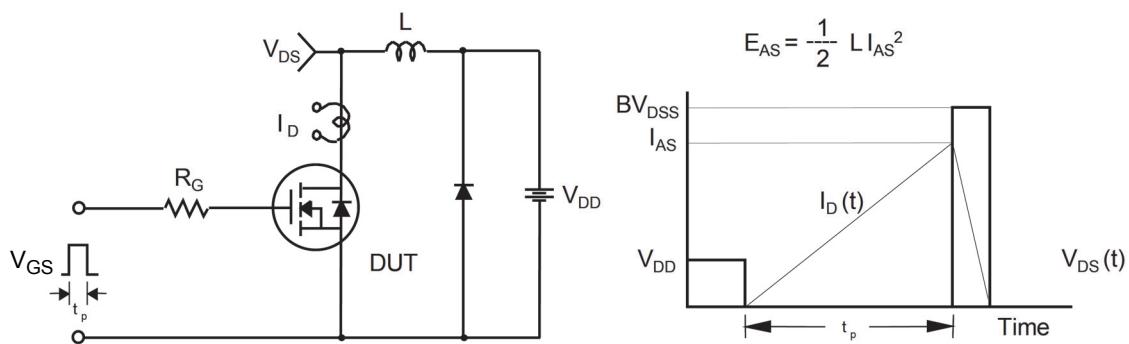


Figure 13. Unclamped Inductive Switching Test Circuit & Waveforms

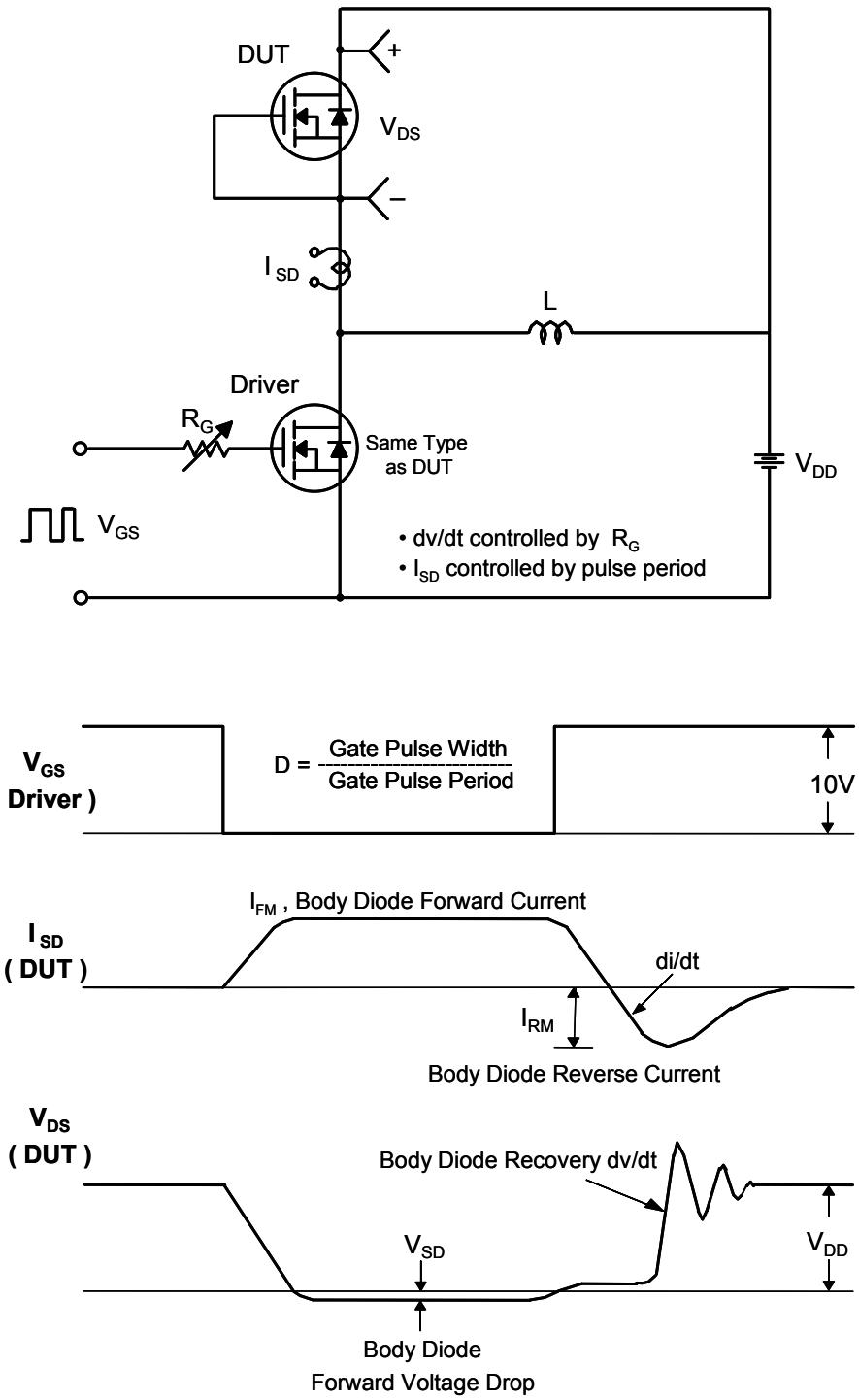


Figure 14. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

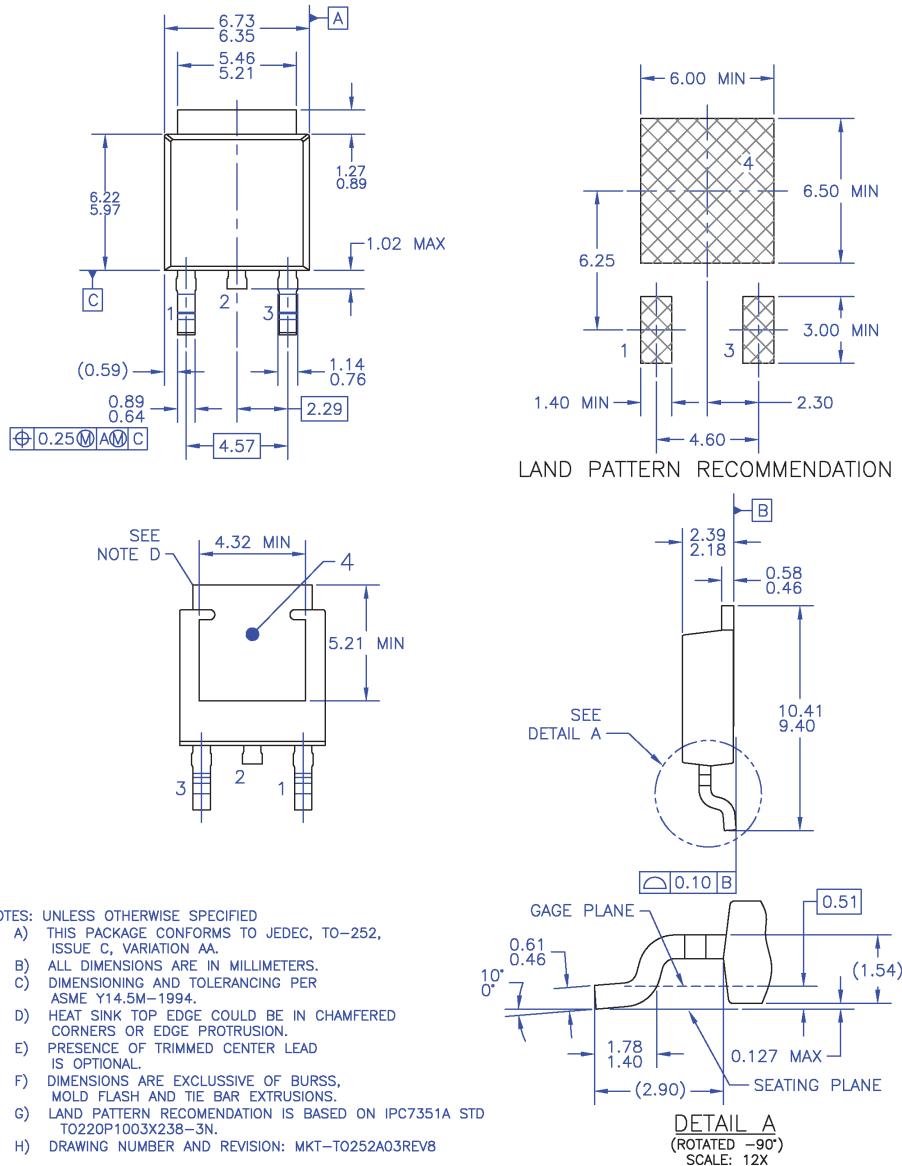


Figure 15. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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